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RESPONSE UNDER 37 C.F.R. 1.116
EXPEDITED PROCEDURE
EXAMINING GROUP 2814

PATENT

Attorney Docket No. 400762/Aoyama

FORM PTO-1083

In re Application of: Suzuki et al.
 Application No. 09/613,749
 Filed: July 11, 2000
 For: Field Effect Transistor Structure With Bent Gate



COMMISSIONER FOR PATENTS
 Washington, D.C. 20231

Sir:

Transmitted herewith is a response to an office action in the subject application.

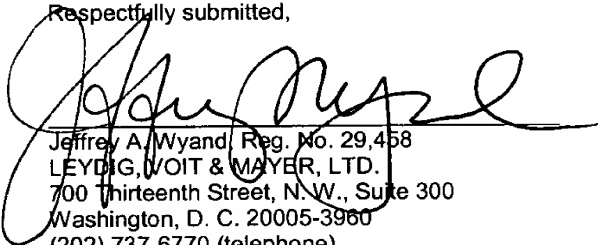
- ☐ Applicants claim small entity status of this application under 37 CFR 1.27.
- ☐ Petition for Extension of Time
- ☐ Applicants petition for a one-month extension of time under 37 CFR 1.136, the fee for which is \$110.00 (enclosed).
- ☐ Applicants believe that no petition for an extension of time is necessary. However, to the extent that such petition is deemed necessary, Applicants hereby petition for a sufficient extension of time to render the present submission timely. Please charge Deposit Account No. 12-1216 for the appropriate petition fee.
- ☒ No additional claim fee is required.
- ☐ Other:

The claim fee has been calculated as shown below:

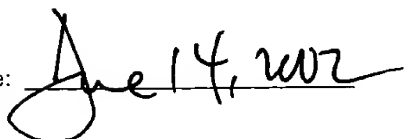
					SMALL ENTITY		OTHER THAN A SMALL ENTITY	
	CLAIMS REMAINING AFTER AMENDMENT		HIGHEST NUMBER PREVIOUSLY PAID FOR	EXTRA CLAIMS PRESENT	RATE	ADDIT. CLAIM FEE	RATE	ADDIT. CLAIM FEE
TOTAL		MINUS		=	x 9=	\$	x 18=	\$
INDEPENDENT		MINUS		=	x 42=	\$	x 84=	\$
<input type="checkbox"/>	FIRST PRESENTATION OF MULTIPLE CLAIM				+ 140=	\$	+ 280=	\$
					TOTAL	\$	TOTAL	\$

- ☐ Please charge my Deposit Account No. 12-1216 in the amount of \$. A duplicate copy of this sheet is attached.
- ☐ A check in the amount of \$ is attached.
- ☒ The Commissioner is hereby authorized to charge any deficiencies in the following fees associated with this communication or credit any overpayment to Deposit Account No. 12-1216. A duplicate copy of this sheet is attached.
- ☒ Any filing fees under 37 CFR 1.16 for the presentation of extra claims.
- ☒ Any patent application processing fees under 37 CFR 1.17.

Respectfully submitted,


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Date:


 June 14, 2002

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V.S.

PATENT
Attorney Docket No. 400762/Aoyama

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

SUZUKI et al.

Application No.: 09/613,749

Art Unit: 2814

Filed: July 11, 2000

Examiner: S. Rao

For: FIELD EFFECT
TRANSISTOR
STRUCTURE WITH
BENT GATE

RESPONSE TO OFFICIAL ACTION PURSUANT TO 37 CFR 1.116

Commissioner for Patents
Washington, D. C. 20231

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Dear Sir:

In response to the Official Action dated April 4, 2002, please enter the following amendments and consider the following remarks.

AMENDMENTS

IN THE CLAIMS

Cancel claims 1-3, 5, 8, 9, and 11-13 and replace the indicated claims with:

4. (Thrice Amended) A semiconductor device comprising:
- (a) an electrically isotropic compound semiconductor substrate having a first surface and a second surface;
 - (b) an active region on the first surface of the substrate;
 - (c) a first semiconductor element in the active region, including